

GENERAL DESCRIPTION

The 8302 is a low skew, 1-to-2 LVCMOS/LVTTL Fanout Buffer. The 8302 hasa single ended clock input. The single endedclock input accepts LVCMOS or LVTTL input levels. The 8302 features a pair of LVCMOS/LVTTL outputs. The 8302 is characterized at full 3.3V for input $V_{\rm DD}$, and mixed 3.3V and 2.5V for output operating supply modes ($V_{\rm DDO}$). Guaranteed output and part-to-part skew characteristics make the 8302 ideal for clock distribution applications demanding well defined performance and repeatibility.

FEATURES

- 2 LVCMOS / LVTTL outputs
- LVCMOS / LVTTL clock input accepts LVCMOS or LVTTL input levels
- Maximum output frequency: 200MHz
- Output skew: 25ps (typical)
- · Part-to-part skew: 250ps (typical)
- Small 8 lead SOIC package saves board space
- Full 3.3V or 3.3V core, 2.5V supply modes
- 0°C to 70°C ambient operating temperature
- · Lead-Free package fully RoHS compliant

BLOCK DIAGRAM



PIN ASSIGNMENT

Vddo 🗌	1	8	Q0
Vdd 🗌	2	7	GND
CLK 🗌	3	6	
GND 🗌	4	5	_Q1

8302 8-Lead SOIC 3.8mm x 4.8mm, x 1.47mm package body **M Package** Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Туре		Description
1, 6	V _{DDO}	Power		Output supply pins.
2	V _{DD}	Power		Core supply pin.
3	CLK	Input	Pulldown	LVCMOS / LVTTL clock input.
4,7	GND	Power		Power supply ground.
5	Q1	Output		Single clock output. LVCMOS / LVTTL interface levels.
8	Q0	Output		Single clock output. LVCMOS / LVTTL interface levels.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
C	Power Dissipation Capacitance	$V_{DD}, V_{DDO} = 3.465 V$		22		pF
C _{PD}	(per output)	$V_{_{DD}} = 3.465$ V, $V_{_{DDO}} = 2.625$ V		16		pF
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
R _{out}	Output Impedance		5	7	12	Ω

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DD}	4.6V
Inputs, V _I	-0.5V to V _{DD} + 0.5 V
Outputs, V _o	-0.5V to V_{DDO} + 0.5V
Package Thermal Impedance, $\boldsymbol{\theta}_{_{JA}}$	112.7°C/W (0 lfpm)
Storage Temperature, T _{STG}	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the DC Characteristics or AC Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 3A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, TA = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V _{DDO}	Output Power Supply Voltage		3.135	3.3	3.465	V
I _{DD}	Power Supply Current				13	mA
I _{DDO}	Output Supply Current				4	mA

TABLE 3B. LVCMOS / LVTTL DC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, TA = 0°C to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage			2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage			-0.3		0.8	V
I _{IH}	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$			150	μA
I _{IL}	Input Low Current	CLK	$V_{DD} = 3.465 V, V_{IN} = 0 V$	-5			μA
V	Output High Voltage		50 Ω to V _{DDO} /2	2.6			V
V _{он}	Output High Voltage		I _{OH} = -100μA	2.9			V
V			50 Ω to V _{DDO} /2			0.5	V
V _{ol}	Output Low Voltage		I _{OL} = 100μΑ			0.2	V

TABLE 4A. AC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, TA = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low-to-High; NOTE 1	$f \le 200 \text{MHz}$	1.9	2.35	2.8	ns
<i>t</i> sk(o)	Output Skew; NOTE 2, 4			25	85	ps
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 3, 4			250	800	ps
t _R	Output Rise Time	20% to 80%	300		800	ps
t _F	Output Fall Time	20% to 80%	300		800	ps
odc	Output Duty Cycle	<i>f</i> ≤ 133MHz	45		55	%
Juc	Output Duty Cycle	133MHz < <i>f</i> ≤ 200MHz	40		60	%

Parameters measured at f_{MAX} unless otherwise noted. NOTE 1: Measured from $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at V_{DDO}/2. NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{npc}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V _{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I _{DD}	Power Supply Current				13	mA
I _{DDO}	Output Supply Current				4	mA

TABLE 3C. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, Ta = 0°C to 70°C

TABLE 3D. LVCMOS / LVTTL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, TA = 0°C to 70°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage			2		V _{DD} + 0.3	V
V _{IL}	Input Low Voltage			-0.3		0.8	V
I _{IH}	Input High Current	CLK	$V_{DD} = V_{IN} = 3.465V$			150	μA
I _{IL}	Input Low Current	CLK	V _{DD} = 3.465V, V _{IN} = 0V	-5			μA
V	Output High Voltage		50 Ω to V _{DDO} /2	1.8			V
V _{OH}			Ι _{ΟΗ} = -100μΑ	2.2			V
V			50 Ω to V _{DDO} /2			0.5	V
V _{OL}	Output Low Voltage		I _{OL} = 100μA			0.2	V

Table 4B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f _{MAX}	Output Frequency				200	MHz
tp _{LH}	Propagation Delay, Low-to-High; NOTE 1	$f \le 200 \text{MHz}$	2.3		3.3	ns
tsk(o)	Output Skew; NOTE 2, 4				85	ps
tsk(pp)	Part-to-Part Skew; NOTE 3, 4			250	800	ps
t _R	Output Rise Time	20% to 80%	250		650	ps
t _F	Output Fall Time	20% to 80%	250		650	ps
odc	Output Duty Cycle	<i>f</i> ≤ 133MHz	45		55	%
ouc	Output Duty Cycle	133MHz < <i>f</i> ≤ 200MHz	40		60	%

Parameters measured at f_{MAX} unless otherwise noted. NOTE 1: Measured from $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.

NOTE 2: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at $V_{_{DDO}}/2$. NOTE 3: Defined as skew between outputs on different devices operating at the same supply voltages

and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at $V_{DDO}/2$.

NOTE 4: This parameter is defined in accordance with JEDEC Standard 65.

PARAMETER MEASUREMENT INFORMATION



RELIABILITY INFORMATION

Table 5. $\boldsymbol{\theta}_{JA} \text{vs.}$ Air Flow Table for 8 Lead SOIC

	0	200	500
ingle-Layer PCB, JEDEC Standard Test Boards	153.3°C/W	128.5°C/W	115.5°C/W
Iulti-Layer PCB, JEDEC Standard Test Boards	112.7°C/W	103.3°C/W	97.1°C/W

TRANSISTOR COUNT

The transistor count for 8302 is: 322

PACKAGE OUTLINE - SUFFIX M FOR 8 LEAD SOIC



TABLE 6. PACKAGE DIMENSIONS

CYMDOL	Millin	neters
SYMBOL	MINIMUN	MAXIMUM
N	8	3
A	1.35	1.75
A1	0.10	0.25
В	0.33	0.51
С	0.19	0.25
D	4.80	5.00
E	3.80	4.00
е	1.27 E	BASIC
н	5.80	6.20
h	0.25	0.50
L	0.40	1.27
α	0°	8°

Reference Document: JEDEC Publication 95, MS-012

TABLE 7. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8302AMLF	8302AMLF	8 lead "Lead Free" SOIC	tube	0°C to 70°C
8302AMLFT	8302AMLF	8 lead "Lead Free" SOIC	tape & reel	0°C to 70°C

REVISION HISTORY SHEET					
Rev	Table	Page	Description of Change	Date	
в	T1 T2 T3A & T3C T4A & T4B	2 2 3, 4 3, 4	Pin Description table, revised V _{DD} description. Pin Characteristics table, deleted R _{PULLUP} row. Power Supply table, changed V _{DD} parameter to correspond with description. AC Characteristics tables - added note "Parameters measured at f _{MAX} unless otherwise noted." tp _{LH} Test Conditions, added f ≤ 200MHz.	2/4/03	
С	T2 T7	2 8	Pin Chararcteristics table - changed C _{IN} 4pF max. to 4pF typical. Added 5 Ω min. and 12 Ω max. to R _{OUT} row. Ordering Information table - added "Lead-Free" part number.	6/15/04	
D	T3B & T3D T7	3, 4 8	LVCMOS DC Characteristics Table - changed V_{μ} max. from 1.3V to 0.8V. Ordering Information Table - added Lead-Free note.	5/17/05	
D	Τ7	8 10	Updated datasheet's header/footer with IDT from ICS. Removed ICS prefix from Part/Order Number column. Added Contact Page.	7/30/10	
D	T7	8	Ordering Information - removed leaded devices. Updated data sheet format.	11/19/15	
D			Updated header and footer.	3/4/16	



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